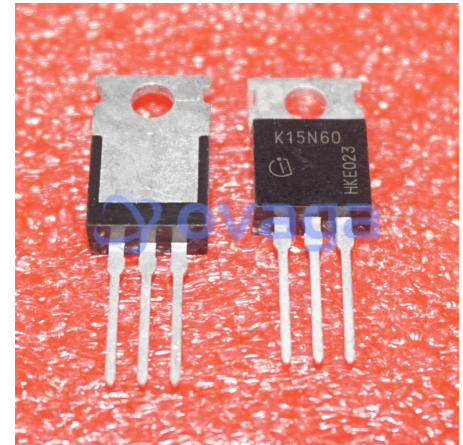


Fast S-IGBT in NPT-technology with soft, fast recovery anti-parallel EmCon diode NPT S-IGBT

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-220
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for SKP15N60 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

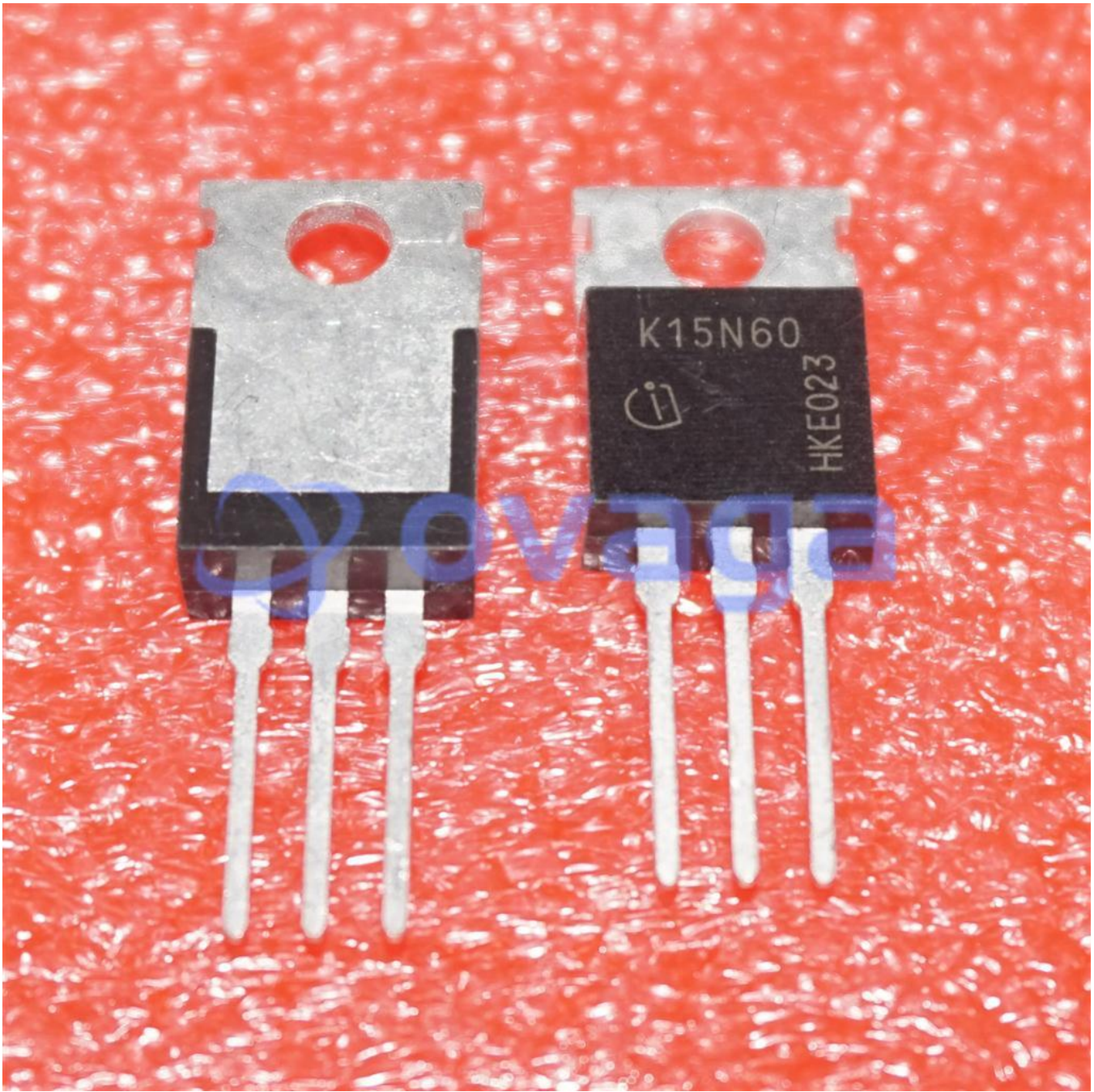
SKP15N60 is a specific model of a power MOSFET transistor that is designed to handle high voltage and high current applications. Here are some features of SKP15N60:

Features

- Voltage Rating: 600V
- Current Rating: 15A
- Low On-Resistance: 0.3 Ohms
- Fast Switching Speed: 40ns
- Avalanche Energy Specified

Application

- Power Supplies
- Motor Control
- Lighting Applications
- Audio Amplifiers
- Switching Regulators





Related Products



[SKP06N60](#)

Infineon Technologies Corporation
TO-220



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



[BSC011N03LS](#)

Infineon Technologies Corporation
PG-TDSON-8



[IPP60R070CFD7](#)

Infineon Technologies Corporation
TO-220-3



[IPB180N06S4-H1](#)

Infineon Technologies Corporation
PG-TO263-7-3



[IPG20N04S4-12](#)

Infineon Technologies Corporation
TDSO8-8



[IPW65R080CFD](#)

Infineon Technologies Corporation
TO-247



[IPD25N06S4L-30](#)

Infineon Technologies Corporation
PG-TO252-3